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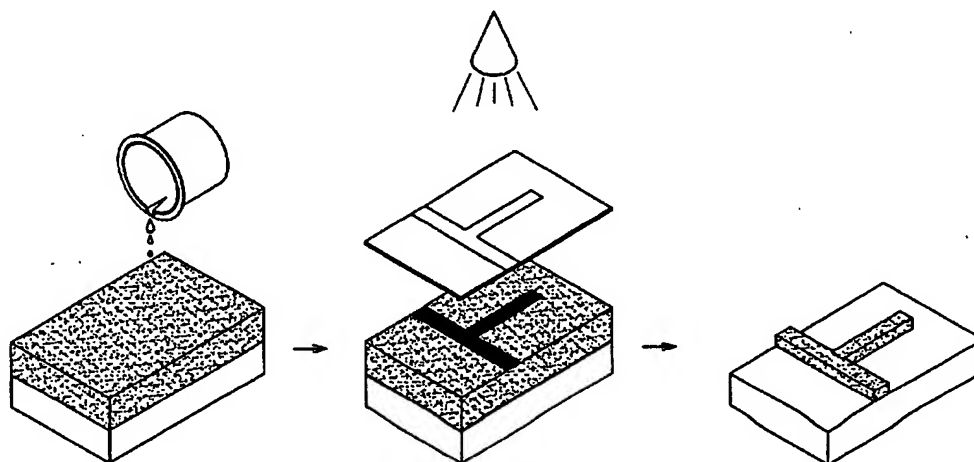
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(54) Title: **A METHOD OF FORMING A METAL PATTERN AND A METHOD OF FABRICATING TFT ARRAY PANEL BY USING THE SAME**



(57) Abstract: With a metal pattern formation process and a method of manufacturing a thin film transistor array panel using the metal pattern formation process, an organometallic layer is formed by coating an organometallic complex containing metal. The organometallic layer is exposed to light through a photo mask, and developed to form a metal pattern.

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